

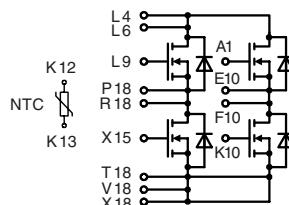
CoolMOS Power MOSFET

in ECO-PAC 2

N-Channel Enhancement Mode
Low R_{DSon} , High V_{DSS} MOSFET
Package with Electrically Isolated Base

Preliminary data sheet

$I_{D25} = 38 \text{ A}$
 $V_{DSS} = 600 \text{ V}$
 $R_{DSon} = 70 \text{ m}\Omega$



COOLMOS[®]
Power Semiconductors

Pin arrangement see outlines

MOSFET

Symbol	Conditions	Maximum Ratings		
V_{DSS}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	600		V
V_{GS}		± 20		V
I_{D25}	$T_c = 25^\circ\text{C}$	38		A
I_{D90}	$T_c = 90^\circ\text{C}$	25		A
dv/dt	$V_{DS} < V_{DSS}$; $I_F \leq 50\text{A}$; $ di_F/dt \leq 200\text{A}/\mu\text{s}$ $T_{VJ} = 150^\circ\text{C}$	6		V/ns
E_{AS}	$I_D = 10 \text{ A}$; $L = 36 \text{ mH}$; $T_c = 25^\circ\text{C}$	1.8		J
E_{AR}	$I_D = 20 \text{ A}$; $L = 5 \mu\text{H}$; $T_c = 25^\circ\text{C}$	1		mJ

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)		
R_{DSon}	$V_{GS} = 10 \text{ V}$; $I_D = I_{D90}$			70 m Ω
V_{GSth}	$V_{DS} = 20 \text{ V}$; $I_D = 3 \text{ mA}$	3.5		5.5 V
I_{DSS}	$V_{DS} = V_{DSS}$; $V_{GS} = 0 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		60	25 μA μA
I_{GSS}	$V_{GS} = \pm 20 \text{ V}$; $V_{DS} = 0 \text{ V}$			100 nA
Q_g Q_{gs} Q_{gd}	$V_{GS} = 10 \text{ V}$; $V_{DS} = 350 \text{ V}$; $I_D = 50 \text{ A}$		220 55 125	nC nC nC
$t_{d(on)}$ t_r $t_{d(off)}$ t_f	$V_{GS} = 10 \text{ V}$; $V_{DS} = 380 \text{ V}$ $I_D = 25 \text{ A}$; $R_G = 1.8 \Omega$		30 95 100 10	ns ns ns ns
V_F	(reverse conduction) $I_F = 20 \text{ A}$; $V_{GS} = 0 \text{ V}$	0.9	1.1	V
R_{thJC}	per MOSFET			0.45 K/W

Data according to IEC 60747 refer to a single diode or transistor unless otherwise stated

¹⁾ CoolMOS is a trademark of Infineon Technologies AG.

IXYS reserves the right to change limits, test conditions and dimensions.

© 2005 IXYS All rights reserved

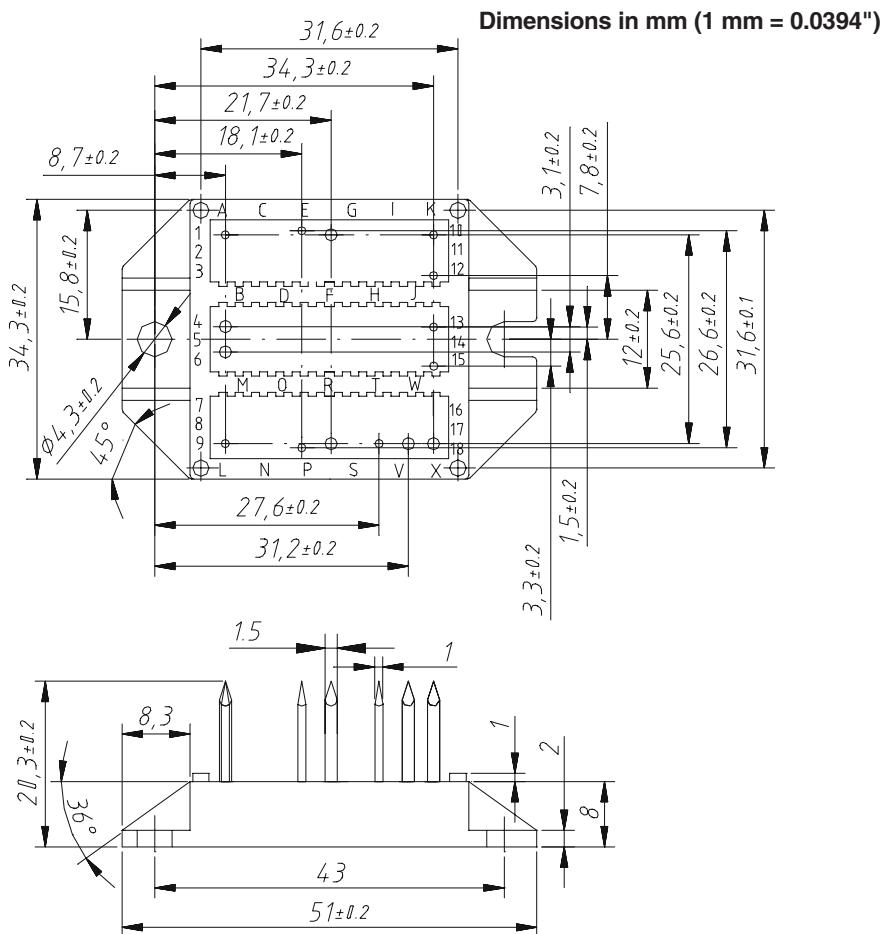
Temperature Sensor NTC

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
R_{25}	$T = 25^\circ\text{C}$	4.75	5.0	5.25 $\text{k}\Omega$
$B_{25/50}$			3375	K

Module

Symbol	Conditions	Maximum Ratings		
T_{VJ}		-40...+150	$^\circ\text{C}$	
T_{stg}		-40...+125	$^\circ\text{C}$	
V_{ISOL}	$I_{\text{ISOL}} \leq 1 \text{ mA}; 50/60 \text{ Hz}; t = 1 \text{ s}$	3600	V~	
M_d	mounting torque (M4)	1.5 - 2.0 14 - 18	Nm lb.in.	
a	Max. allowable acceleration	50	m/s^2	

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
d_s	Creepage distance on surface (Pin to heatsink)	11.2		mm
d_A	Strike distance in air (Pin to heatsink)	11.2		mm
Weight		24		g



IXYS reserves the right to change limits, test conditions and dimensions.